



## SINGLE CHANNEL HIGH SIDE DRIVER

**Table 1. General Features**

TYPE	R <sub>DS(on)</sub>	I <sub>OUT</sub>	V <sub>CC</sub>
VN920PEP-E	15mΩ	30 A	36 V

- CMOS COMPATIBLE INPUT
- PROPORTIONAL LOAD CURRENT SENSE
- SHORTED LOAD PROTECTION
- UNDERVOLTAGE AND OVERVOLTAGE SHUTDOWN
- OVERVOLTAGE CLAMP
- THERMAL SHUTDOWN
- CURRENT LIMITATION
- PROTECTION AGAINST LOSS OF GROUND AND LOSS V<sub>CC</sub>
- VERY LOW STAND-BY POWER DISSIPATION
- REVERSE BATTERY PROTECTION (\*)
- IN COMPLIANCE WITH THE 2002/95/EC EUROPEAN DIRECTIVE

### DESCRIPTION

The VN920PEP-E is a monolithic device designed in STMicroelectronics VIPower M0-3 Technology, intended for driving any kind of load with one side connected to ground. Active V<sub>CC</sub> pin voltage clamp protects the device against low energy spikes (see ISO7637 transient compatibility table).

**Figure 1. Package**



Active current limitation combined with thermal shutdown and automatic restart protect the device against overload. The device integrates an analog current sense output which delivers a current proportional to the load current. Device automatically turns off in case of ground pin disconnection.

**Table 2. Order Codes**

Package	Tube	Tape and Reel
PowerSSO-24	VN920PEP-E	VN920PEPTR-E

Note: (\*) See application schematic at page 10

Figure 2. Block Diagram

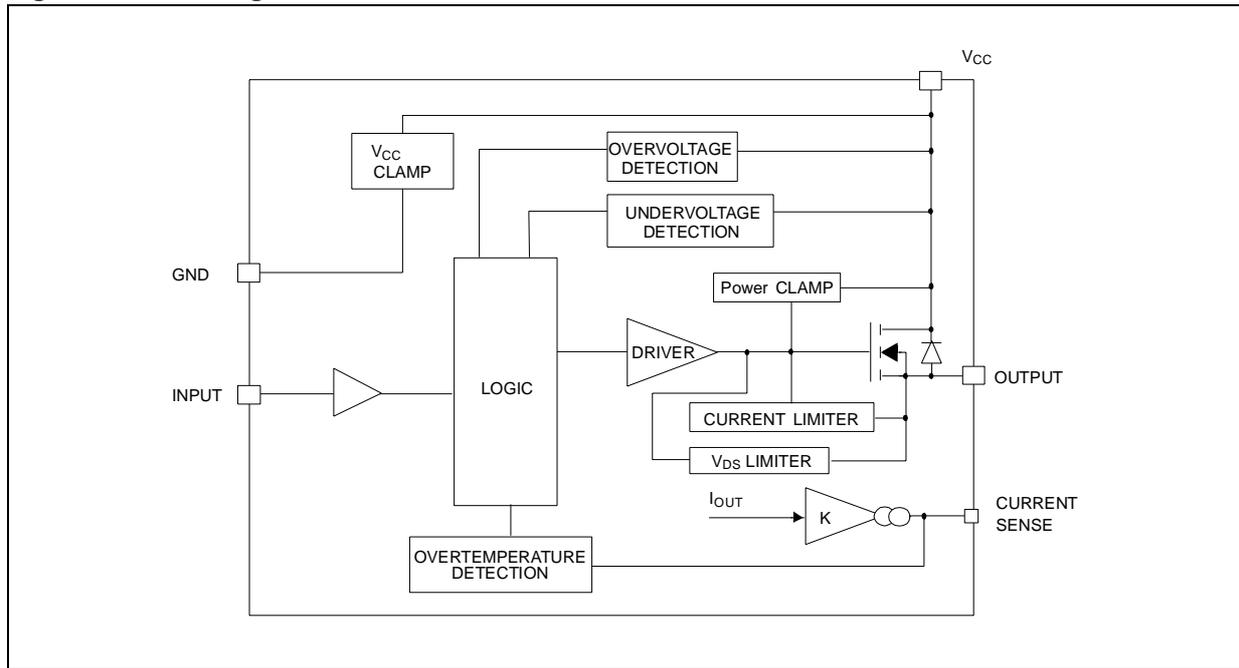


Table 3. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	41	V
-V <sub>CC</sub>	Reverse DC Supply Voltage	- 0.3	V
- I <sub>GND</sub>	DC Reverse Ground Pin Current	- 200	mA
I <sub>OUT</sub>	DC Output Current	Internally Limited	A
- I <sub>OUT</sub>	Reverse DC Output Current	- 40	A
I <sub>IN</sub>	DC Input Current	+/- 10	mA
V <sub>CSENSE</sub>	Current Sense Maximum Voltage	-3 +15	V V
V <sub>ESD</sub>	Electrostatic Discharge (Human Body Model: R=1.5KΩ; C=100pF)		
	- INPUT	4000	V
	- CURRENT SENSE	2000	V
	- OUTPUT	5000	V
	- V <sub>CC</sub>	5000	V
E <sub>MAX</sub>	Maximum Switching Energy (L=0.3mH; R <sub>L</sub> =0Ω; V <sub>bat</sub> =13.5V; T <sub>jstart</sub> =150°C; I <sub>L</sub> =45A)	462	mJ
P <sub>tot</sub>	Power Dissipation T <sub>C</sub> ≤25°C	96	W
T <sub>j</sub>	Junction Operating Temperature	Internally limited	°C
T <sub>C</sub>	Case Operating Temperature	- 40 to 150	°C
T <sub>STG</sub>	Storage Temperature	- 55 to 150	°C

Figure 3. Configuration Diagram (Top View) & Suggested Connections for Unused and N.C. Pins

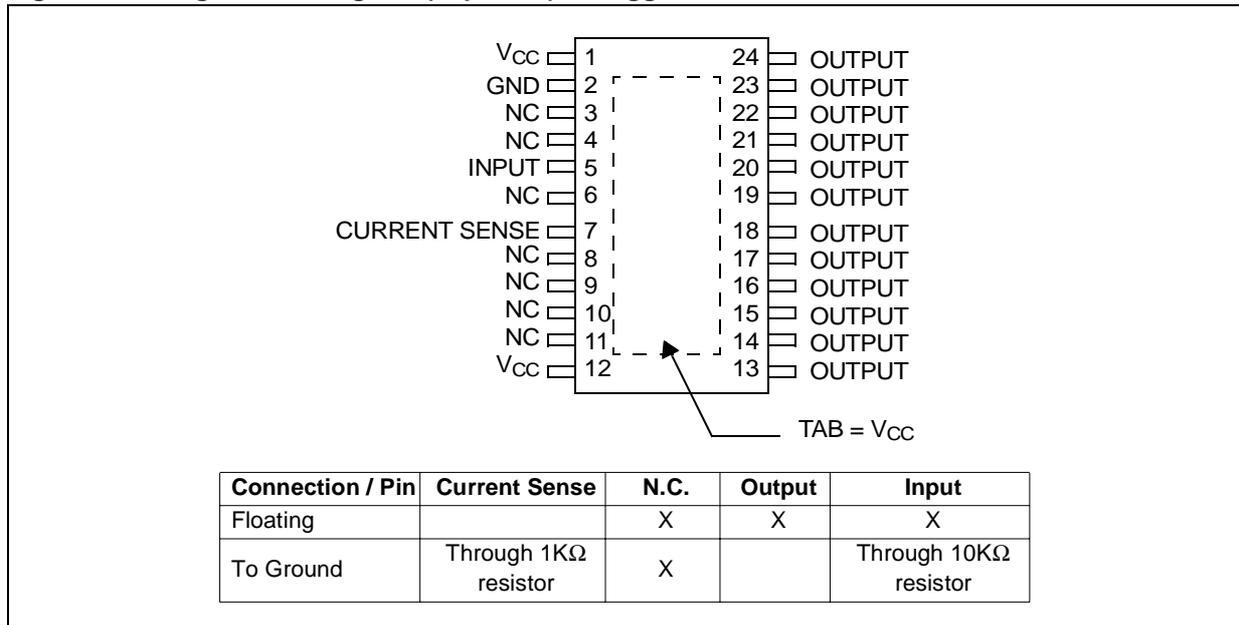


Figure 4. Current and Voltage Conventions

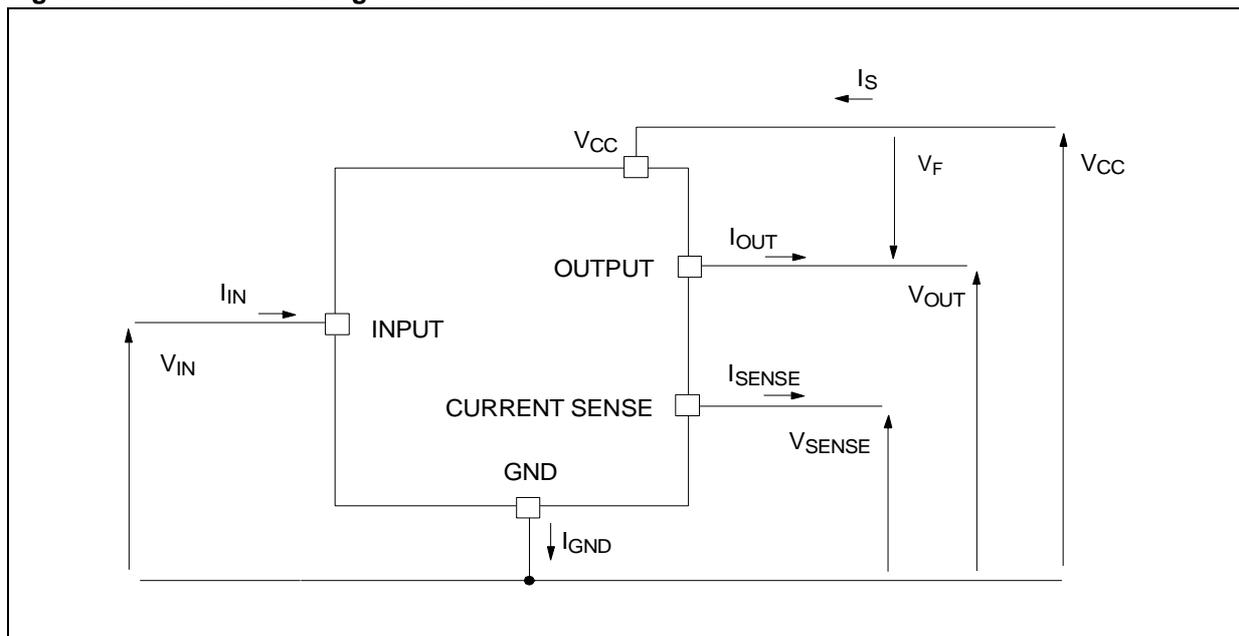


Table 4. Thermal Data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal Resistance Junction-case	Max 1.3	°C/W
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max 55 <sup>(1)</sup> 40 <sup>(2)</sup>	°C/W

Note: (1) When mounted on a standard single-sided FR-4 board with 0.5cm<sup>2</sup> of Cu (at least 35μm thick).

Note: (2) When mounted on a standard single-sided FR-4 board with 8cm<sup>2</sup> of Cu (at least 35μm thick).

**ELECTRICAL CHARACTERISTICS** ( $8V < V_{CC} < 36V$ ;  $-40^{\circ}C < T_j < 150^{\circ}C$  unless otherwise specified)

**Table 5. Power**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{CC}$	Operating Supply Voltage		5.5	13	36	V
$V_{USD}$	Undervoltage Shut-down		3	4	5.5	V
$V_{OV}$	Overvoltage Shut-down		36			V
$R_{ON}$	On State Resistance	$I_{OUT}=10A$ ; $T_j=25^{\circ}C$			15	m $\Omega$
		$I_{OUT}=10A$			30	m $\Omega$
		$I_{OUT}=3A$ ; $V_{CC}=6V$			50	m $\Omega$
$V_{clamp}$	Clamp Voltage	$I_{CC}=20mA$ (See note 1)	41	48	55	V
$I_S$	Supply Current	Off State; $V_{CC}=13V$ ; $V_{IN}=V_{OUT}=0V$		10	25	$\mu A$
		Off State; $V_{CC}=13V$ ; $T_j=25^{\circ}C$ ; $V_{IN}=V_{OUT}=0V$		10	20	$\mu A$
		On State; $V_{CC}=13V$ ; $V_{IN}=5V$ ; $I_{OUT}=0$ ; $R_{SENSE}=3.9K\Omega$			5	mA
$I_{L(off1)}$	Off State Output Current	$V_{IN}=V_{OUT}=V_{SENSE}=0V$	0		50	$\mu A$
$I_{L(off3)}$	Off State Output Current	$V_{IN}=V_{OUT}=V_{SENSE}=0V$ ; $V_{CC}=13V$ ; $T_j=125^{\circ}C$			5	$\mu A$
$I_{L(off4)}$	Off State Output Current	$V_{IN}=V_{OUT}=V_{SENSE}=0V$ ; $V_{CC}=13V$ ; $T_j=25^{\circ}C$			3	$\mu A$

Note: 1.  $V_{clamp}$  and  $V_{OV}$  are correlated. Typical difference is 5V.

**Table 6. Switching** ( $V_{CC} = 13V$ )

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on Delay Time	$R_L=1.3\Omega$ (see figure 2)		50		$\mu s$
$t_{d(off)}$	Turn-off Delay Time	$R_L=1.3\Omega$ (see figure 2)		50		$\mu s$
$dV_{OUT}/dt_{(on)}$	Turn-on Voltage Slope	$R_L=1.3\Omega$ (see figure 2)		See relative diagram		V/ $\mu s$
$dV_{OUT}/dt_{(off)}$	Turn-off Voltage Slope	$R_L=1.3\Omega$ (see figure 2)		See relative diagram		V/ $\mu s$

**Table 7. Logic Input**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{IL}$	Input Low Level				1.25	V
$I_{IL}$	Low Level Input Current	$V_{IN}=1.25V$	1			$\mu A$
$V_{IH}$	Input High Level		3.25			V
$I_{IH}$	High Level Input Current	$V_{IN}=3.25V$			10	$\mu A$
$V_{I(hyst)}$	Input Hysteresis Voltage		0.5			V
$V_{ICL}$	Input Clamp Voltage	$I_{IN}=1mA$	6	6.8	8	V
		$I_{IN}=-1mA$		-0.7		V

## ELECTRICAL CHARACTERISTICS (continued)

Table 8. Current Sense ( $9V \leq V_{CC} \leq 16V$ ) (See figure 5)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
K <sub>1</sub>	I <sub>OUT</sub> /I <sub>SENSE</sub>	I <sub>OUT</sub> =1A; V <sub>SENSE</sub> =0.5V; T <sub>j</sub> = -40°C...150°C	3300	4400	6000	
dK <sub>1</sub> /K <sub>1</sub>	Current Sense Ratio Drift	I <sub>OUT</sub> =1A; V <sub>SENSE</sub> =0.5V; T <sub>j</sub> = -40°C...+150°C	-10		+10	%
K <sub>2</sub>	I <sub>OUT</sub> /I <sub>SENSE</sub>	I <sub>OUT</sub> =10A; V <sub>SENSE</sub> =4V; T <sub>j</sub> =-40°C T <sub>j</sub> =25°C...150°C	4200 4400	4900 4900	6000 5750	
dK <sub>2</sub> /K <sub>2</sub>	Current Sense Ratio Drift	I <sub>OUT</sub> =10A; V <sub>SENSE</sub> =4V; T <sub>j</sub> =-40°C...+150°C	-8		+8	%
K <sub>3</sub>	I <sub>OUT</sub> /I <sub>SENSE</sub>	I <sub>OUT</sub> =30A; V <sub>SENSE</sub> =4V; T <sub>j</sub> =-40°C T <sub>j</sub> =25°C...150°C	4200 4400	4900 4900	5500 5250	
dK <sub>3</sub> /K <sub>3</sub>	Current Sense Ratio Drift	I <sub>OUT</sub> =30A; V <sub>SENSE</sub> =4V; T <sub>j</sub> =-40°C...+150°C	-6		+6	%
I <sub>SENSE0</sub>	Analog Sense Leakage Current	V <sub>CC</sub> =6...16V; I <sub>OUT</sub> =0A; V <sub>SENSE</sub> =0V; T <sub>j</sub> =-40°C...+150°C	0		10	μA
V <sub>SENSE</sub>	Max Analog Sense Output Voltage	V <sub>CC</sub> =5.5V; I <sub>OUT</sub> =5A; R <sub>SENSE</sub> =10KΩ V <sub>CC</sub> >8V; I <sub>OUT</sub> =10A; R <sub>SENSE</sub> =10KΩ	2 4			V V
V <sub>SENSEH</sub>	Sense Voltage in Overtemperature conditions	V <sub>CC</sub> =13V; R <sub>SENSE</sub> =3.9KΩ		5.5		V
R <sub>VSENSEH</sub>	Analog sense output impedance in overtemperature condition	V <sub>CC</sub> =13V; T <sub>j</sub> >T <sub>TSD</sub> ; Output Open		400		Ω
t <sub>DSENSE</sub>	Current sense delay response	to 90% I <sub>SENSE</sub> (see note 2)			500	μs

Note: 2. Current sense signal delay after positive input slope

Table 9. Protections (See note 3)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
T <sub>TSD</sub>	Shut-down Temperature		150	175	200	°C
T <sub>R</sub>	Reset Temperature		135			°C
T <sub>hyst</sub>	Thermal Hysteresis		7	15		°C
I <sub>lim</sub>	DC Short Circuit Current	V <sub>CC</sub> =13V 5V<V <sub>CC</sub> <36V	30	45	75 75	A A
V <sub>demag</sub>	Turn-off Output Clamp Voltage	I <sub>OUT</sub> =2A; V <sub>IN</sub> =0V; L=6mH	V <sub>CC</sub> -41	V <sub>CC</sub> -48	V <sub>CC</sub> -55	V
V <sub>ON</sub>	Output Voltage Drop Limitation	I <sub>OUT</sub> =1A; T <sub>j</sub> =-40°C....+150°C		50		mV

Note: 3. To ensure long term reliability under heavy overload or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device is subjected to abnormal conditions, this software must limit the duration and number of activation cycles.

ELECTRICAL CHARACTERISTICS (continued)

Table 10. V<sub>CC</sub> - Output Diode

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V <sub>F</sub>	Forward on Voltage	-I <sub>OUT</sub> =5.3A; T <sub>J</sub> =150°C			0.6	V

Figure 5. I<sub>OUT</sub>/I<sub>SENSE</sub> versus I<sub>OUT</sub>

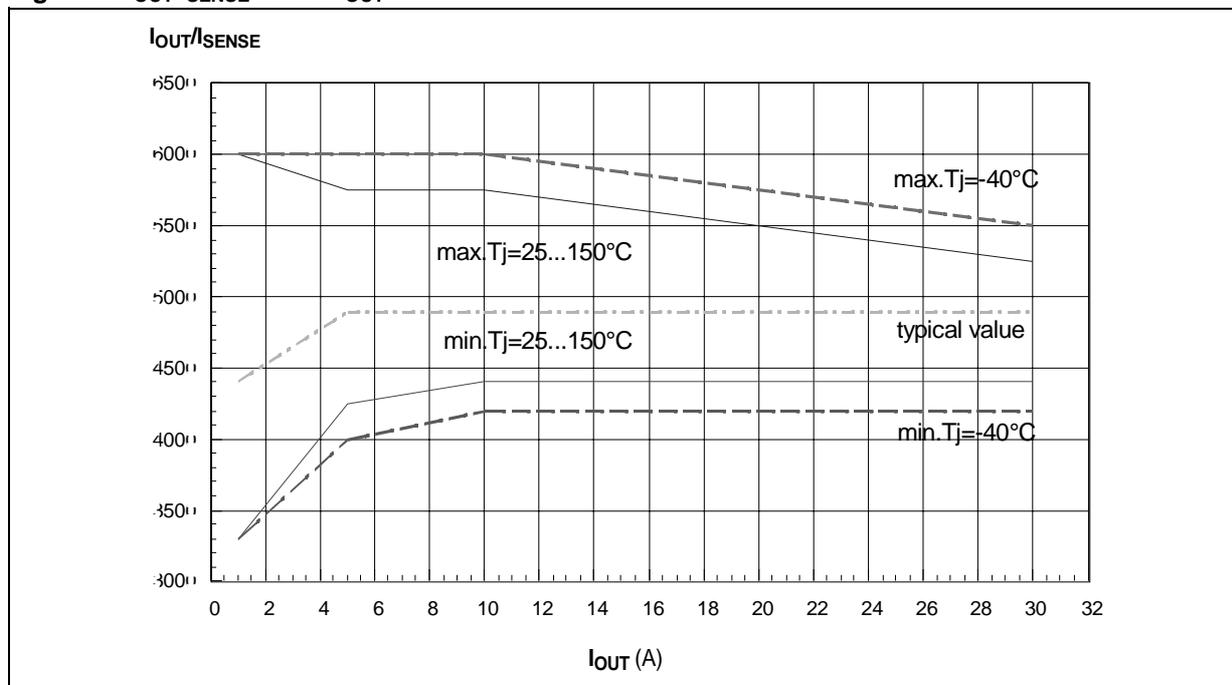
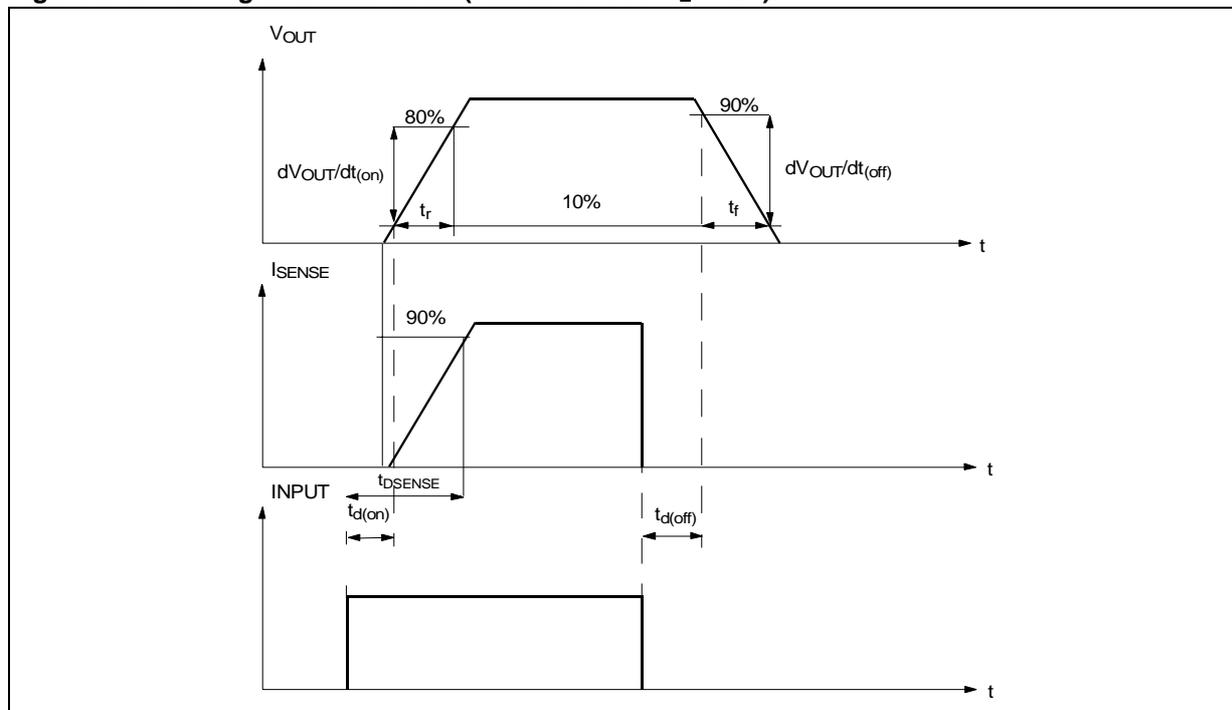


Figure 6. Switching Characteristics (Resistive load R<sub>L</sub>=1.3Ω)



**Table 11. Truth Table**

CONDITIONS	INPUT	OUTPUT	SENSE
Normal operation	L	L	0
	H	H	Nominal
Overtemperature	L	L	0
	H	L	$V_{SENSEH}$
Undervoltage	L	L	0
	H	L	0
Overvoltage	L	L	0
	H	L	0
Short circuit to GND	L	L	0
	H	L	$(T_j < T_{TSD})$ 0
	H	L	$(T_j > T_{TSD})$ $V_{SENSEH}$
Short circuit to $V_{CC}$	L	H	0
	H	H	< Nominal
Negative output voltage clamp	L	L	0

**Figure 7. Switching time Waveforms**

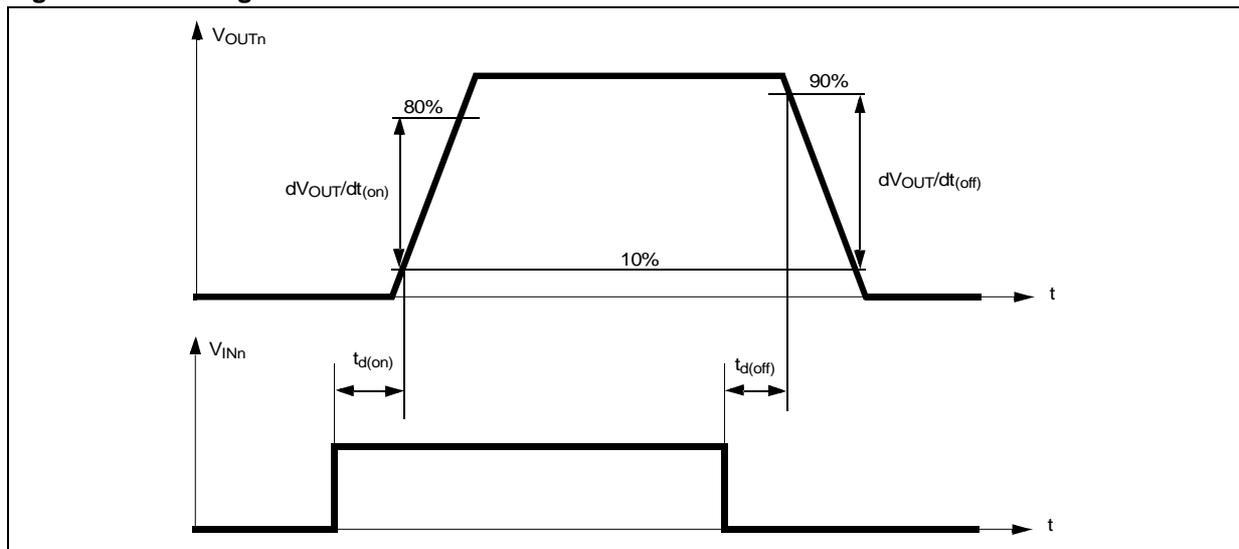


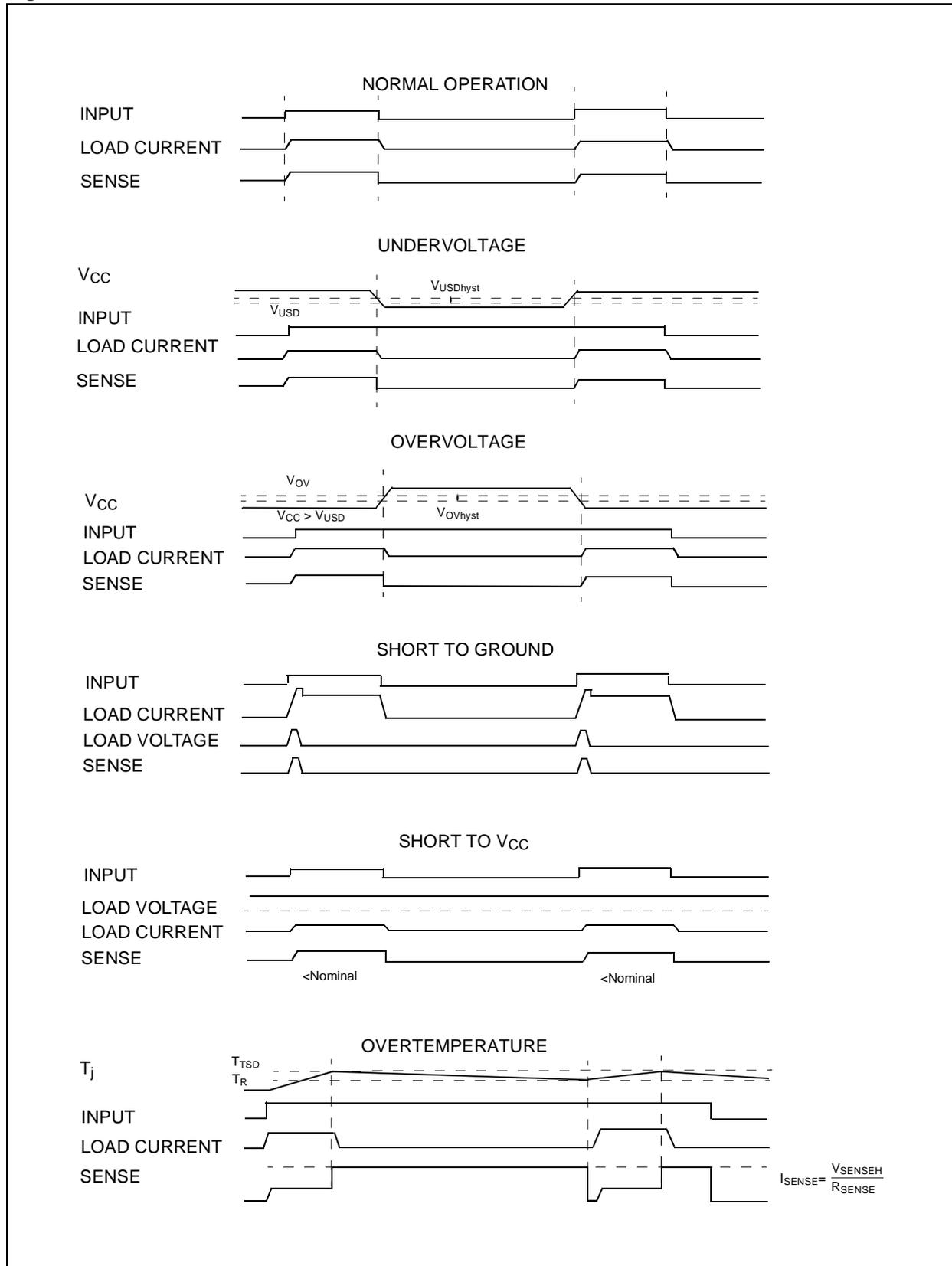
Table 12. Electrical Transient Requirements on V<sub>CC</sub> Pin

ISO T/R 7637/1 Test Pulse	TEST LEVELS				Delays and Impedance
	I	II	III	IV	
1	-25 V	-50 V	-75 V	-100 V	2 ms 10 Ω
2	+25 V	+50 V	+75 V	+100 V	0.2 ms 10 Ω
3a	-25 V	-50 V	-100 V	-150 V	0.1 μs 50 Ω
3b	+25 V	+50 V	+75 V	+100 V	0.1 μs 50 Ω
4	-4 V	-5 V	-6 V	-7 V	100 ms, 0.01 Ω
5	+26.5 V	+46.5 V	+66.5 V	+86.5 V	400 ms, 2 Ω

ISO T/R 7637/1 Test Pulse	TEST LEVELS RESULTS			
	I	II	III	IV
1	C	C	C	C
2	C	C	C	C
3a	C	C	C	C
3b	C	C	C	C
4	C	C	C	C
5	C	E	E	E

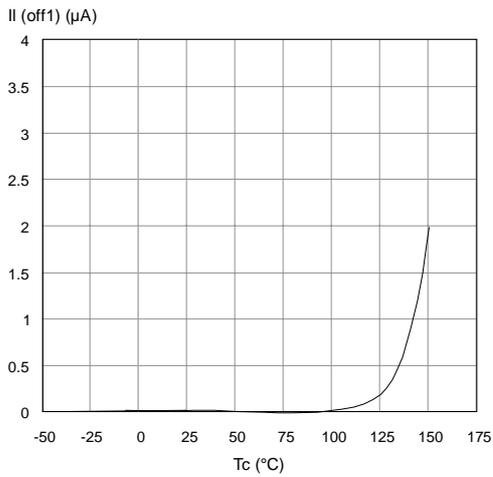
CLASS	CONTENTS
C	All functions of the device are performed as designed after exposure to disturbance.
E	One or more functions of the device is not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device.

Figure 8. Waveforms

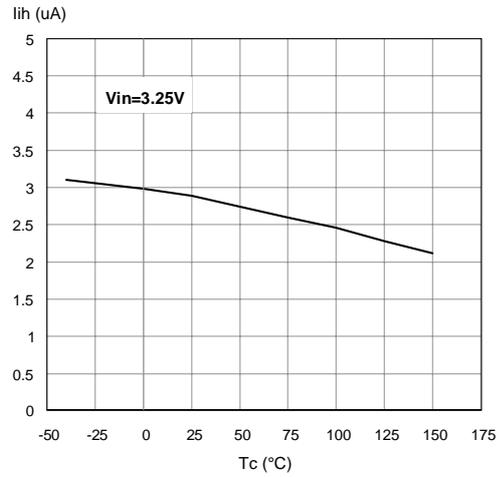




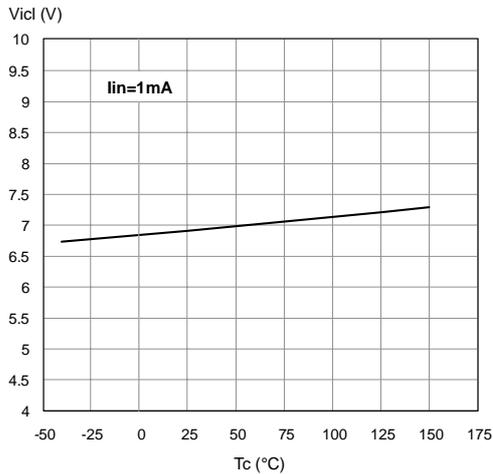
**Figure 10. Off State Output Current**



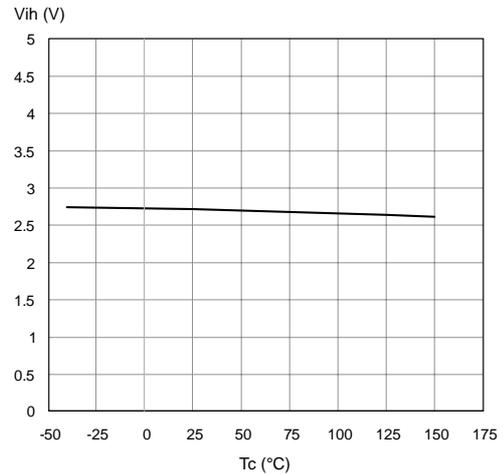
**Figure 11. High Level Input Current**



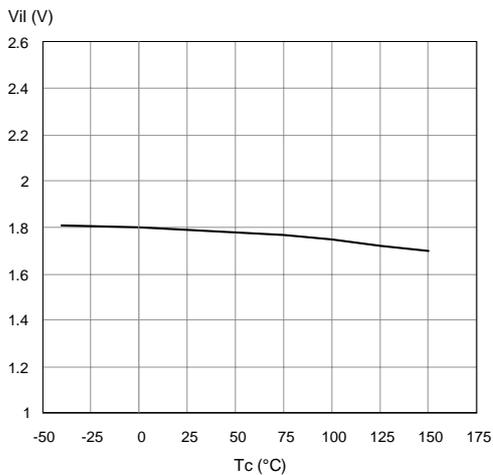
**Figure 12. Input Clamp Voltage**



**Figure 14. Input High Level**



**Figure 13. Input Low Level**



**Figure 15. Input Hysteresis Voltage**

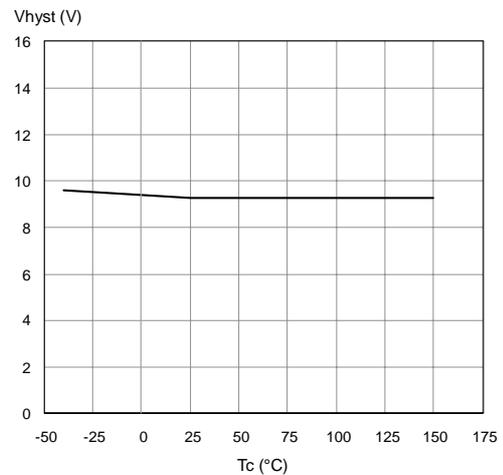


Figure 16. Overvoltage Shutdown

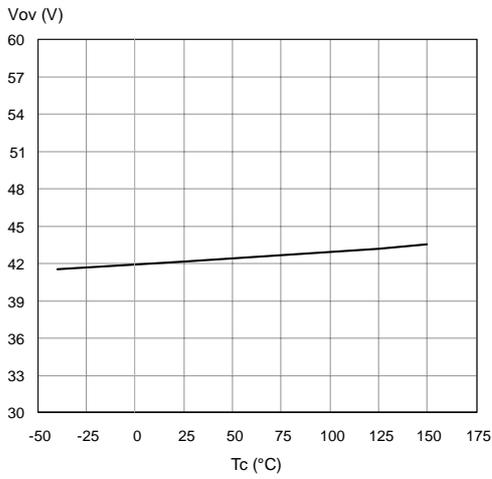


Figure 19. I<sub>LIM</sub> Vs T<sub>case</sub>

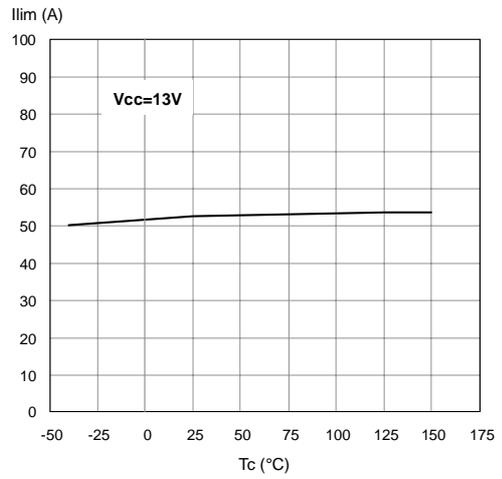


Figure 17. Turn-on Voltage Slope

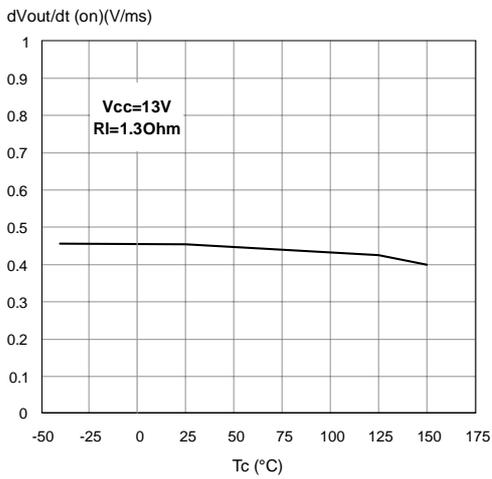


Figure 20. Turn-off Voltage Slope

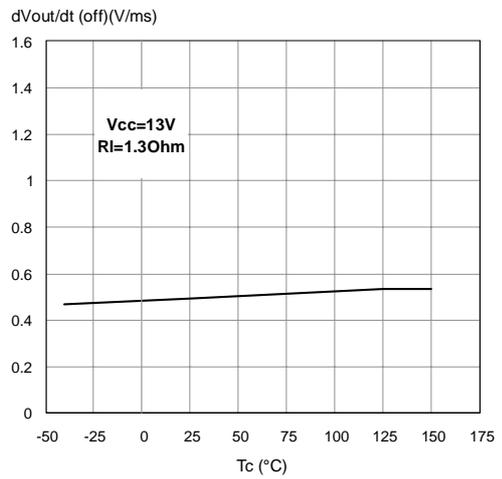
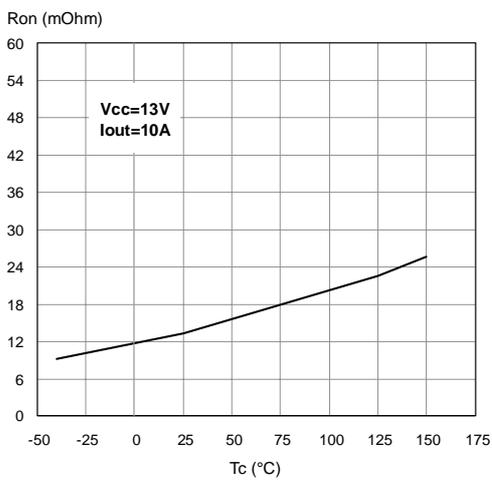


Figure 18. On State Resistance Vs T<sub>case</sub>



PowerSSO-24 Thermal Data

Figure 21. PowerSSO-24 PC Board

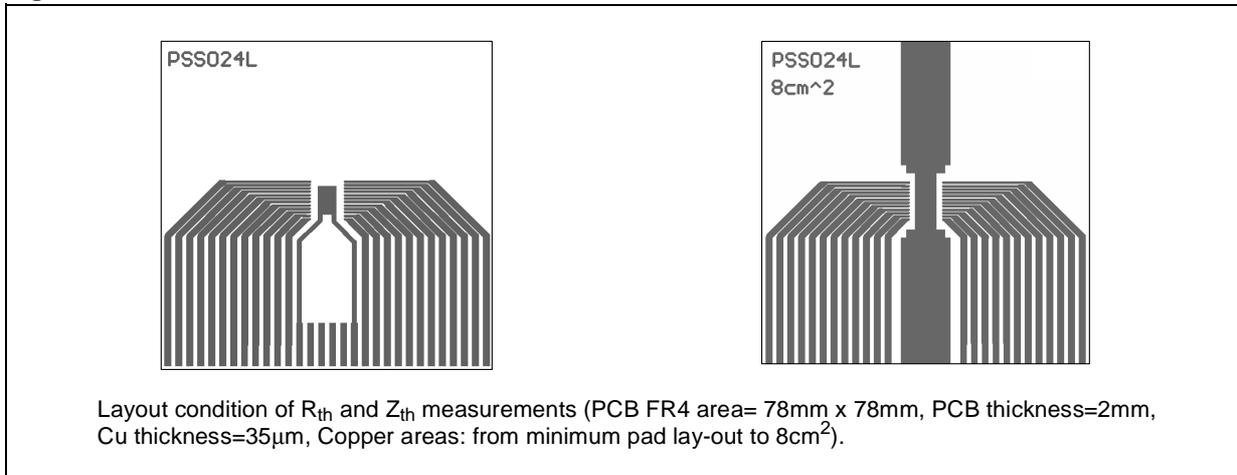


Figure 22.  $R_{thj-amb}$  Vs PCB copper area in open box free air condition

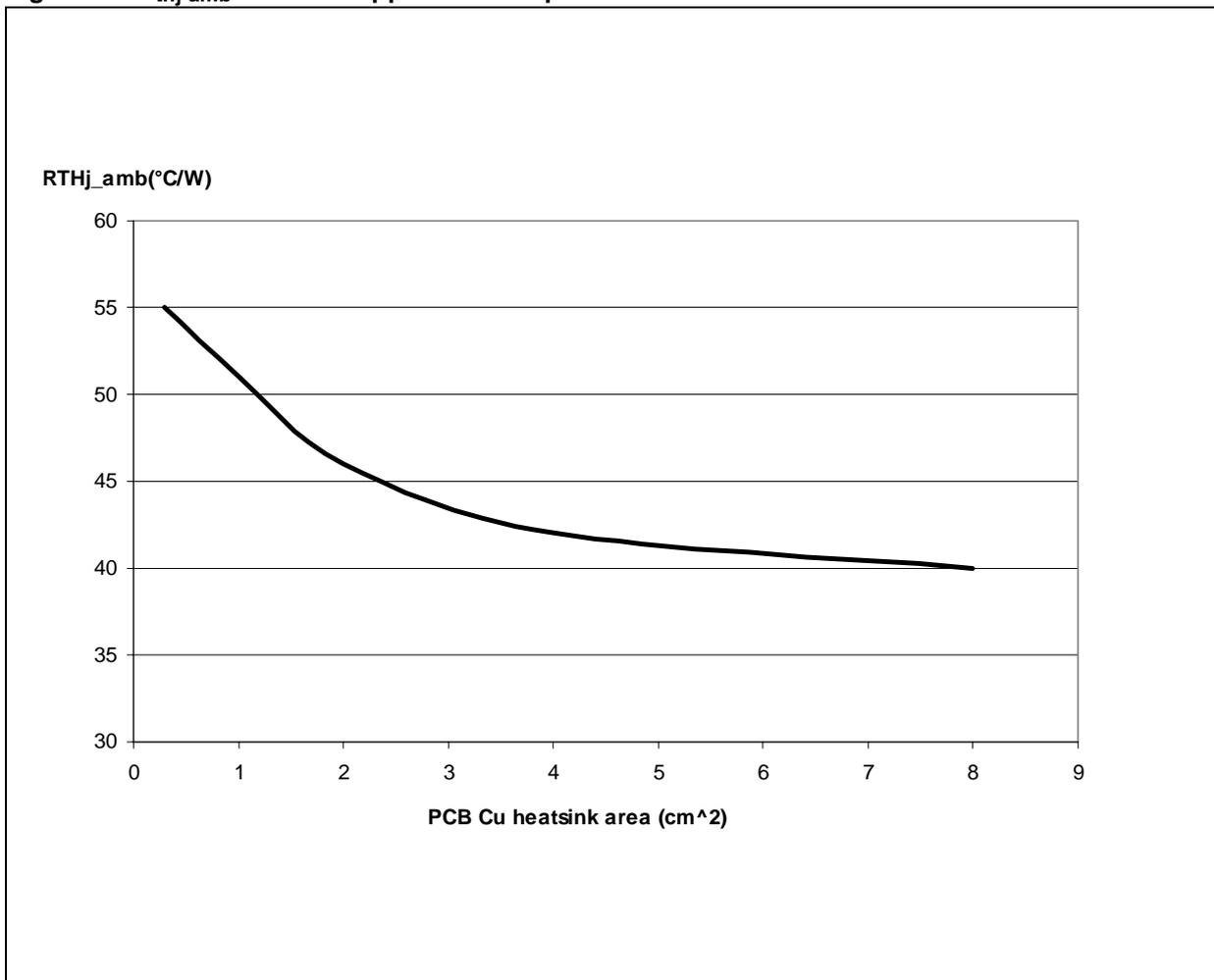
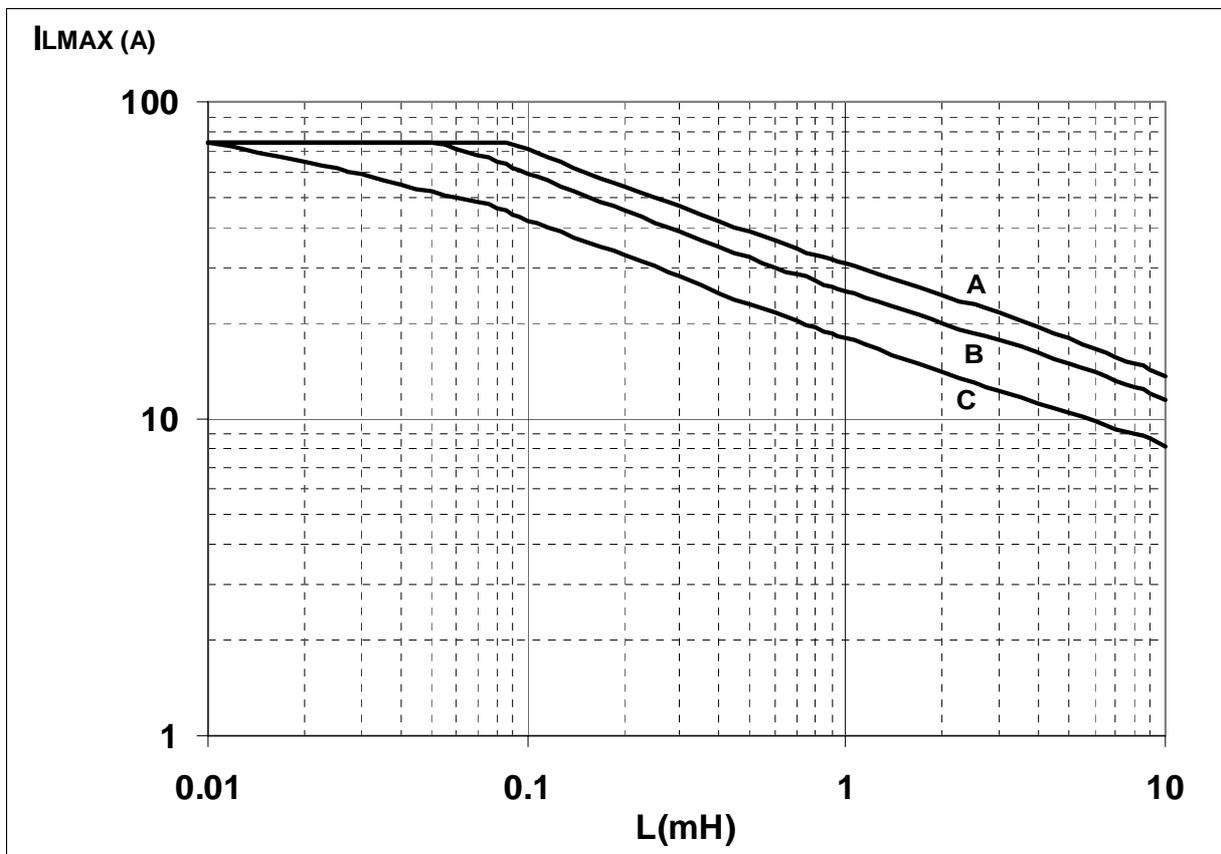


Figure 23. Maximum turn off current versus load inductance



- A = Single Pulse at  $T_{Jstart}=150^{\circ}C$
- B= Repetitive pulse at  $T_{Jstart}=100^{\circ}C$
- C= Repetitive Pulse at  $T_{Jstart}=125^{\circ}C$

Values are generated with  $R_L=0\Omega$

In case of repetitive pulses,  $T_{Jstart}$  (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves B and C.

Conditions:

$V_{CC}=13.5V$

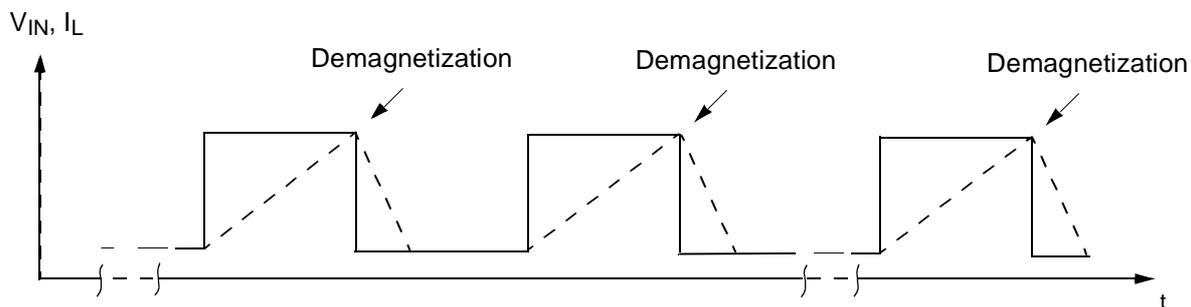


Figure 24. PowerSSO-24 Thermal Impedance Junction Ambient Single Pulse

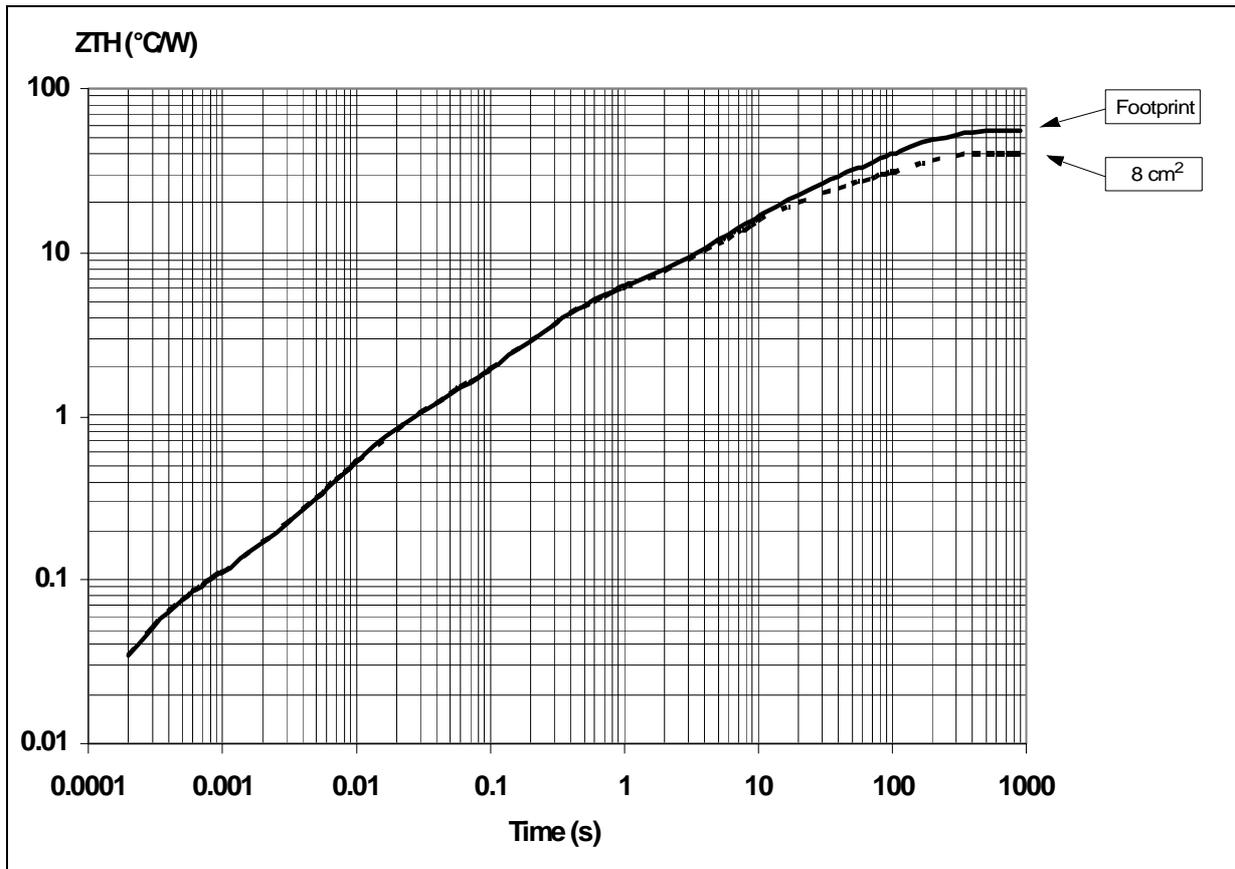
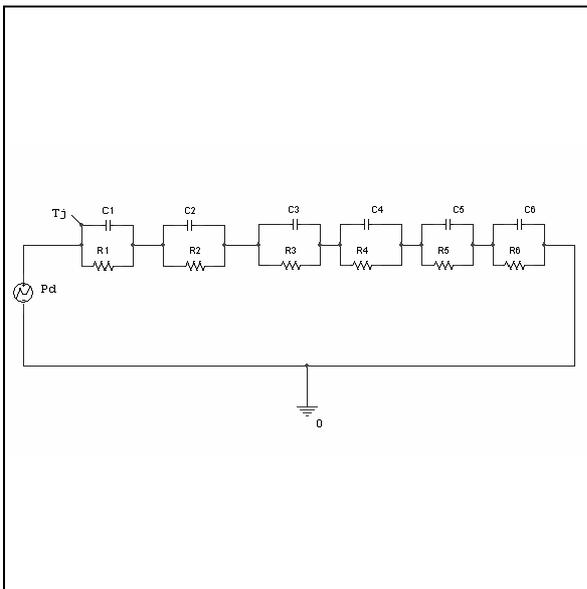


Figure 25. Thermal Fitting Model of a Single Channel HSD in PowerSSO-24



**Pulse Calculation Formula**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where  $\delta = t_p/T$

Table 13. Thermal Parameter

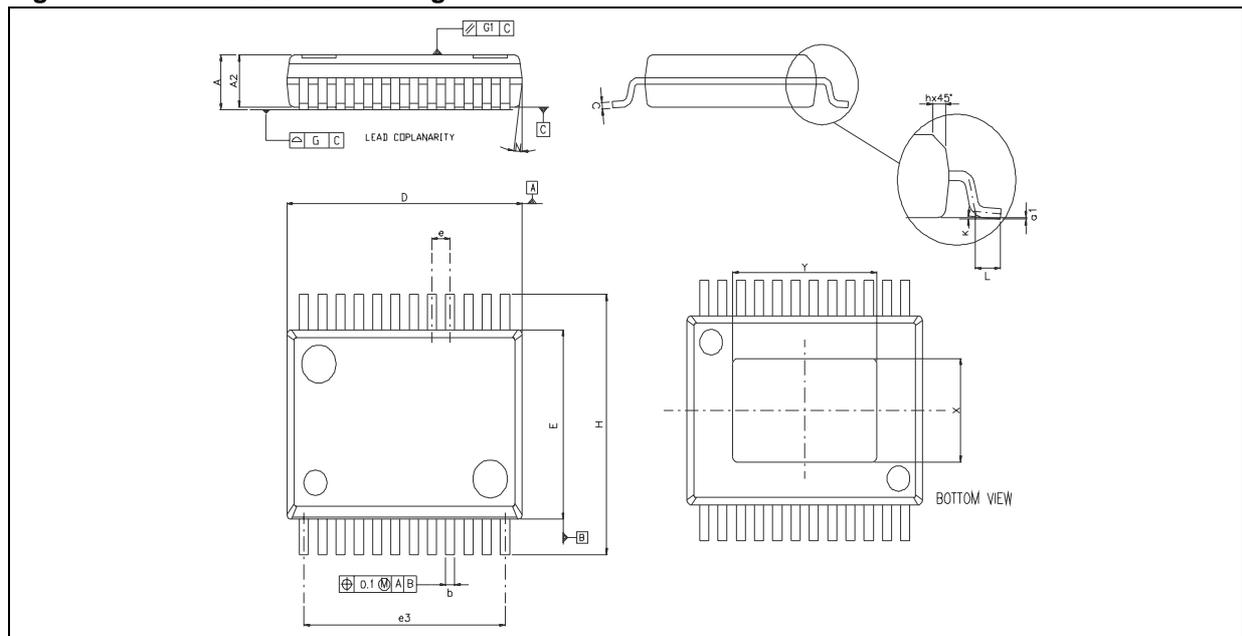
	Area/island (cm <sup>2</sup> )	Footprint	8
R1 (°C/W)		0.012	
R2 (°C/W)		0.05	
R3 (°C/W)		0.65	
R4 (°C/W)		4	
R5 (°C/W)		13.5	
R6 (°C/W)		37	22
C1 (W.s/°C)		0.0004	
C2 (W.s/°C)		0.005	
C3 (W.s/°C)		0.022	
C4 (W.s/°C)		0.08	
C5 (W.s/°C)		0.7	
C6 (W.s/°C)		3	5

PACKAGE MECHANICAL

Table 14. PowerSSO-24™ Mechanical Data

Symbol	millimeters		
	Min	Typ	Max
A	2.15		2.47
A2	2.15		2.40
a1	0		0.075
b	0.33		0.51
c	0.23		0.32
D	10.10		10.50
E	7.4		7.6
e		0.8	
e3		8.8	
G			0.1
G1			0.06
H	10.1		10.5
h			0.4
L	0.55		0.85
N			10deg
X	4.1		4.7
Y	6.5		7.1

Figure 26. PowerSSO-24™ Package Dimensions



**REVISION HISTORY****Table 15. Revision History**

<b>Date</b>	<b>Revision</b>	<b>Description of Changes</b>
Oct. 2004	1	- First Issue.
Nov. 2004	2	- Mechanical data updating. - PowerSSO-24 Thermal Charact. insertion
Dec. 2004	3	- PC Board copper area correction.
Dec. 2004	4	- IL <sub>(off2)</sub> removal.
Mar. 2005	5	- Maximum Switching Energy value insertion. - Maximum turn off current versus load inductance curve insertion. - Minor changes.

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